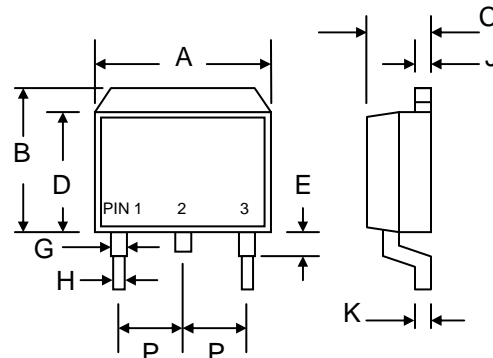


8.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

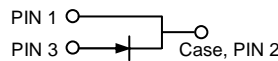
Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



Mechanical Data

- Case: D²PAK/TO-263, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 1.7 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version, Add “-LF” Suffix to Part Number, See Page 4**



D ² PAK/TO-263		
Dim	Min	Max
A	9.80	10.40
B	9.60	10.60
C	4.40	4.80
D	8.50	9.10
E	2.80	—
G	1.00	1.40
H	—	0.90
J	1.20	1.40
K	0.30	0.70
P	2.35	2.75
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SB 820D	SB 830D	SB 840D	SB 845D	SB 850D	SB 860D	SB 880D	SB 8100D	Unit	
Peak Repetitive Reverse Voltage	V _{RRM}	20	30	40	45	50	60	80	100	V	
Working Peak Reverse Voltage	V _{RWM}										
DC Blocking Voltage	V _R										
RMS Reverse Voltage	V _{R(RMS)}	14	21	28	32	35	42	56	70	V	
Average Rectified Output Current @T _C = 130°C	I _O	8.0								A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150								A	
Forward Voltage @I _F = 8.0A	V _{FM}	0.55			0.75		0.85			V	
Peak Reverse Current @T _A = 25°C	I _{RM}	0.5									mA
At Rated DC Blocking Voltage @T _A = 100°C		50									
Typical Junction Capacitance (Note 1)	C _j	350									pF
Typical Thermal Resistance (Note 2)	R _{θJC}	3.0									°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150								°C	

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
2. Mounted on minimum recommended pad size on FR-4 board.

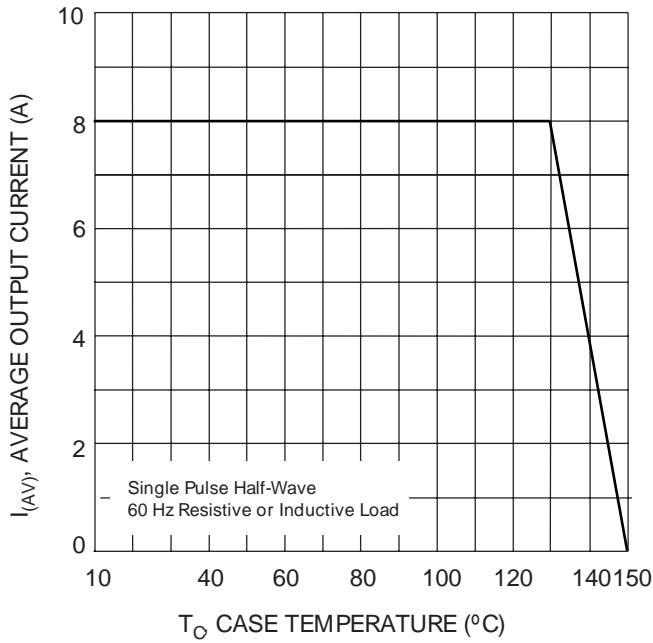


Fig. 1 Forward Current Derating Curve

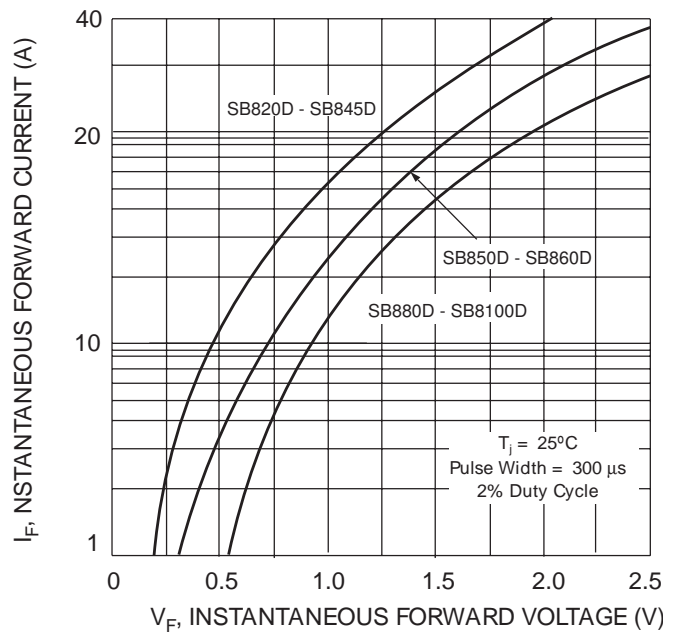


Fig. 2 Typical Forward Characteristics

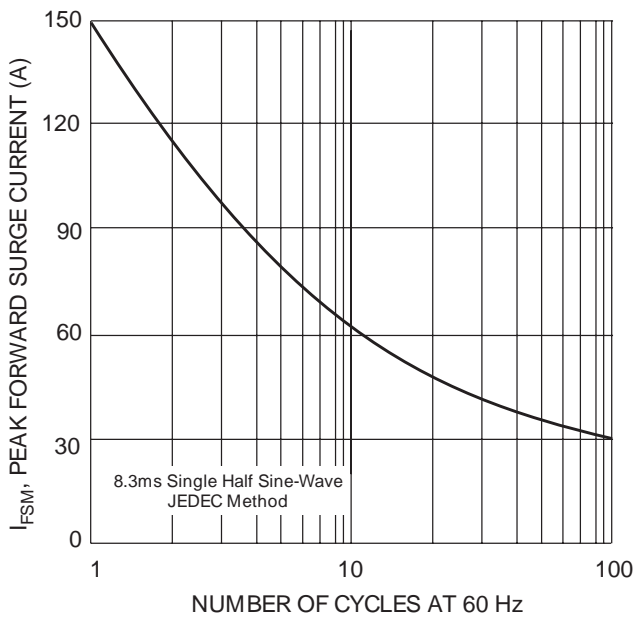


Fig. 3 Maximum Non-Repetitive Peak Fwd Surge Current

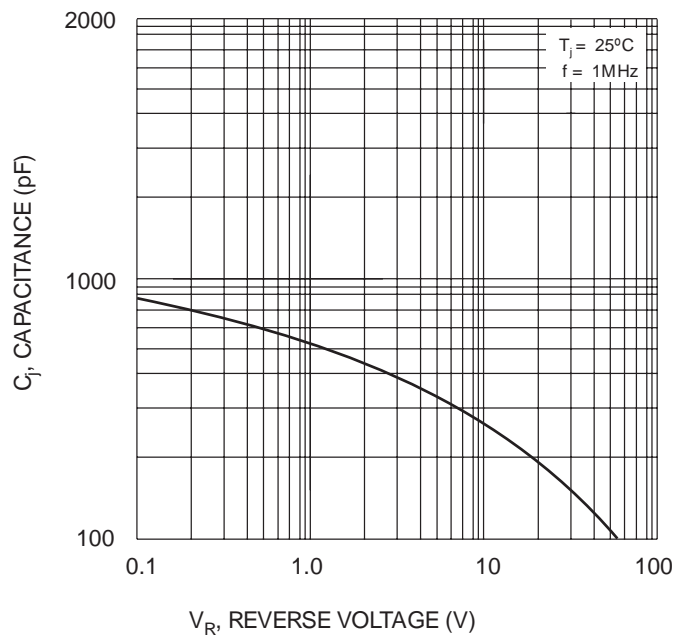


Fig. 4 Typical Junction Capacitance

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
SB820D-T3	D ² PAK	800/Tape & Reel
SB830D-T3	D ² PAK	800/Tape & Reel
SB840D-T3	D ² PAK	800/Tape & Reel
SB845D-T3	D ² PAK	800/Tape & Reel
SB850D-T3	D ² PAK	800/Tape & Reel
SB860D-T3	D ² PAK	800/Tape & Reel
SB880D-T3	D ² PAK	800/Tape & Reel
SB8100D-T3	D ² PAK	800/Tape & Reel

1. Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.
2. **To order RoHS / Lead Free version (with Lead Free finish), add "-LF" suffix to part number above. For example, SB820D-T3-LF.**

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